MGBR30V45C Preliminary DIODE

DUAL MOS GATED BARRIER RECTIFIER

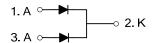
■ DESCRIPTION

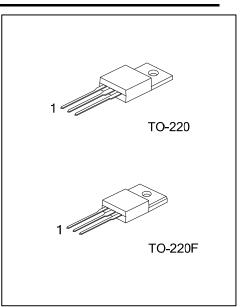
The UTC **MGBR30V45C** is a dual mos gated barrier rectifiers, it uses UT C's a dvanced tech nology to provide cust omers with low forward voltage drop and high switching speed, etc.

■ FEATURES

- * Very low forward voltage drop
- * High switching speed

■ SYMBOL

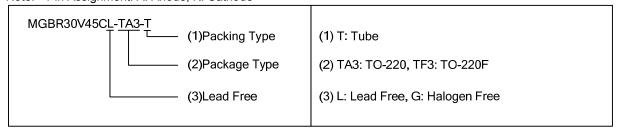




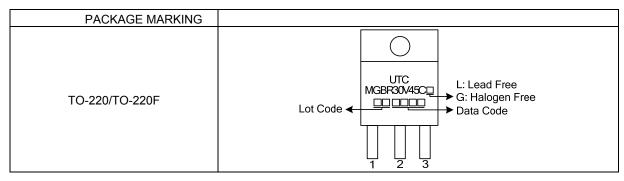
■ ORDERING INFORMATION

Ordering Number		Doolsogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MGBR30V45CL-TA3-T	MGBR30V45CG-TA3-T	TO-220	Α	K	Α	Tube	
MGBR30V45CL-TF3-R	MGBR30V45CG-TF3-R	TO-220F	Α	K	Α	Tube	

Note: Pin Assignment: A: Anode, K: Cathode



■ MARKING INFORMATION



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■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER SYMBOL			RATINGS	UNIT
DC Blocking Voltage		V_{RM} 45		V
Working Peak Reverse Voltage		V _{RWM} 45		V
Peak Repetitive Reverse Voltage		V_{RRM} 45		V
Average Destified Output Current Per Device	Per Leg		15 A	
Average Rectified Output Current Per Device	Total 3	IO	0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I _{FSM} 200		Α
Operating Junction Temperature		T _J -65∼	+150	°C
Storage Temperature		T _{STG} -65	+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient		θ_{JA}	62.5	°C/W	
lumation to Oaca	TO-220	0	2	°C // //	
Junction to Case	TO-220F	$\theta_{ extsf{JC}}$	3.31	°C/W	

■ ELECTRICAL CHARACTERISTICS (PER LEG) (T_A =25°C unless otherwise specified.)

PARAMETER SYM		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.50mA 45				V
Forward Voltage Drop	VEM	I _F =15A, T _J =25°C			0.55	V
		I _F =15A, T _J =125°C			0.50	V
Leakage Current (Note 1)	I PM	V _R =45V, T _J =25°C			500	μA
		V _R =45V, T _J =125°C			100	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

^{2.} Thermal resistance junction to case mounted on heatsink.

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